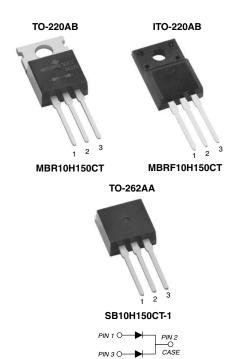
## MBR10H150CT, MBRF10H150CT & SB10H150CT-1

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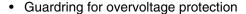
## **Dual Common-Cathode High-Voltage Schottky Rectifier**

Low Leakage Current 5.0 μA



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5 A			
V <sub>RRM</sub>	150 V			
I <sub>FSM</sub>	160 A			
V <sub>F</sub>	0.72 V			
T <sub>J</sub>	175 °C			

#### **FEATURES**





• Low power loss, high efficiency



Low forward voltage drop

• High frequency operation

COMPLIANT

Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in high frequency inverters, freewheeling and polarity protection applications.

#### **MECHANICAL DATA**

**Case:** TO-220AB, ITO-220AB, TO-262AA Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

**Mounting Torque:** 10 in-lbs maximum

Polarity: As marked

PARAMETER	SYMBOL	MBR10H150CT	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	150	V
Working peak reverse voltage	V <sub>RWM</sub>	150	V
Maximum DC blocking voltage	V <sub>DC</sub>	150	V
Maximum average forward rectified current (Fig. 1) total device per diode	I <sub>F(AV)</sub>	10 5	А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	160	А
Peak repetitive reverse current per diode at $t_p = 2 \mu s$ , 1 kHz	I <sub>RRM</sub>	1.0	А
Peak non-repetitive reverse surge energy per diode (8/20 μs waveform)	E <sub>RSM</sub>	10	mJ
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS}$ = 1.5 A, L = 10 mH	E <sub>AS</sub>	11.25	mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min	V <sub>AC</sub>	1500	V

# MBR10H150CT, MBRF10H150CT & SB10H150CT-1

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
	I <sub>F</sub> = 5.0 A	T <sub>J</sub> = 25 °C		0.88		
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	$I_F = 5.0 A$	T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.72	V	
	I <sub>F</sub> = 10 A	$T_J = 25  ^{\circ}C$		0.96		
	I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C		0.80		
Maximum reverse current per diode at working peak reverse voltage (1)		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	5.0 1.0	μA mA	

#### Note:

(1) Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.4	4.5	2.4	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR10H150CT-E3/45	2.06	45	50/tube	Tube		
ITO-220AB	MBRF10H150CT-E3/45	2.20	45	50/tube	Tube		
TO-262AA	SB10H150CT-1E3/45	1.58	45	50/tube	Tube		

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

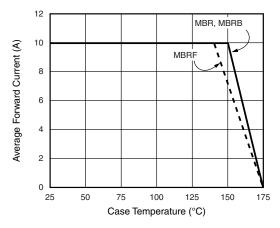


Figure 1. Forward Derating Curve (Total)

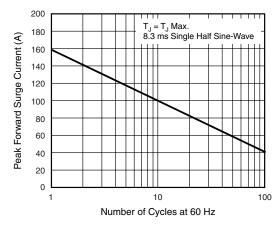


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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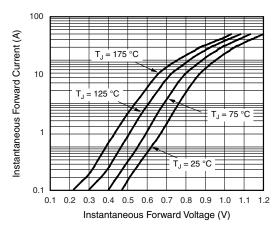


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

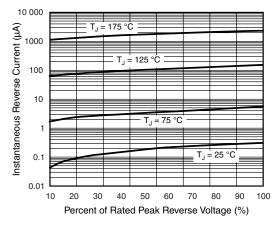


Figure 4. Typical Reverse Characteristics Per Diode

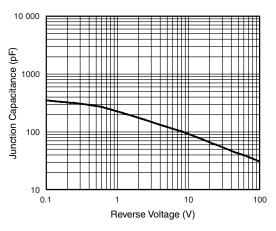


Figure 5. Typical Junction Capacitance Per Diode

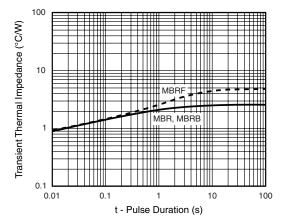


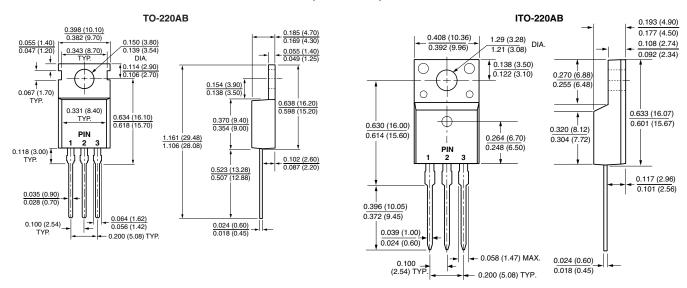
Figure 6. Typical Transient Thermal Impedance Per Diode

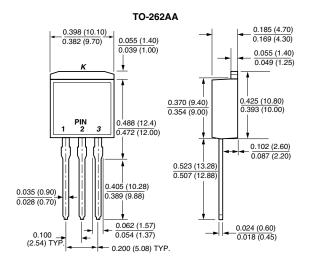
## MBR10H150CT, MBRF10H150CT & SB10H150CT-1

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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







### **Legal Disclaimer Notice**

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